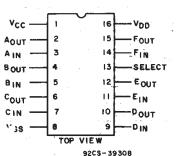


Data sheet acquired from Harris Semiconductor SCHS069D – Revised November 2004



TERMINAL ASSIGNMENT

CD4504B Types

CMOS Hex Voltage-Level Shifter for TTL-to-CMOS or CMOS-to-CMOS Operation

High-Voltage Types (20-Volt Rating)

Features:

- Independence of power-supply sequence considerations-V_{CC} can exceed V_{DD}; input signals can exceed both V_{CC} and V_{DD}
- Up and down level-shifting capability
- Shiftable input threshold for either CMOS or TTL compatibility
- Standardized symmetrical output characteristics
- 100% tested for quiescent current @ 20 V
- Maximum input current of 1 µA at 18 V over full package-temperature range; 100 nA at 18 V and 25° C
- 5 V, 10 V, and 15 V parametric ratings
- Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

■ CD4504B hex voltage level-shifter consists of six circuits which shift input signals from the V_{CC} logic level to the V_{DD} logic level. To shift TTL signals to CMOS logic levels, the SELECT input is at the V_{CC} HIGH logic state. When the SELECT input is at a LOW logic state, each circuit translates signals from one CMOS level to another.

The CD4504B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and MT suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

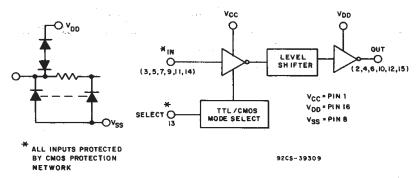


Fig. 1 - Functional diagram for CD4504B.

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	
For T _A = +100°C to +125°C"	Perate Linearity at 12mW/OC to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
OPERATING-TEMPERATURE RANGE (T _A)stORAGE TEMPERATURE RANGE (T _{stg})	85°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max	+265°C

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC			CONDITIONS LIMITS AT INDICATED TEMPERATURES (9C)											Т
CHARACTERISTIC (V) (V) (V) (V) -55 -40 +85 +125 MIN TTP MAX UNITY Quisescent Device Current, IpD Max and ICG In CMOS-CMOS Mode — 0,5 5 5 1.5 1.5 1.5 — 0,02 2 1.5 mA Quisescent Device CMOS Mode — 0,20 5 10 2 2 2 2 — 0,02 2 2 Quisescent Device Current, ICC Max TTL-CMOS Mode — 0,05 5 5 5 5 5 6 6 — 2.5 5 — 0.00 6 0 — 0.02 2 2 2 2 2 2 2 2 2 2 2 2 2 2 0 0.02 4 µA 1 1 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0					1	_		LIMITS A	AT INDICA	TED TEN	PERATU	RES (°C)		1
Curent, Ipp Max and Icc			_	""								1		ļ ·
Current, I _{DD} Max and I _{CC} in CMOS-CMOS Mode − 0,010 5 10 2 2 2 2 2 2 − 0,002 2 1 1 1 1 1 1 1 1			(V)	(V)	(V)	(V)	-55	-40	+85	+125	MIN	TYP	MAX	UNITS
In CMOS-CMOS Mode			_	0,5	5	5	1.5	1.5	1.5	1.5		0.02	1.5	m _A
Culescent Device Current, I _{CC} Max TTL-CMOS Mode				0,10	5	10	2	2	2	2		0.02	2] ""A
Quiescent Device Current, ICC Max TITL-CMOS Mode — 0,5 5 5 5 5 6 6 — 2.5 5 CC Max TITL-CMOS Mode — 0,10 5 10 5 5 6 6 — 2.5 5 Output Low (Sink) 0.4 0.5 — 5 0.84 0.61 0.42 0.36 0.51 1 — Current, IoL Min 0.5 0,10 — 10 1.6 1.5 1.1 0.99 1.3 2.6 — Output High (Source) 4.8 0.5 — 5 -0.64 -0.61 -0.42 -0.33 -0.51 —1 — Current, IoH Min 1.5 0,15 — 15 -2.2 -1.8 -1.3 -0.51 —1 — Current, IoH Min — -5 0.0 —1 0.0 —1 0.0 —1 0.0 —1 0.0 —1 0.0 —1 0.0				0,15	5	15	4	4	120	120	_	0.02	4	μА
CC Max TIL-CMOS Mode		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	-	0,20	5	20	20	20	600	600	_	0.04	20]
Composition				0, 5	5	5	5	5	6	6		2.5	5	
Cutput Low (Sink) Current, IoL Min 0.4 0.5 — 5 0.64 0.61 0.42 0.36 0.51 1 — Part of the pa	ICC wax I I	L-CMOS Mode		0, 10	5	10	5	5	6	6	_	2.5	5	mA
Current, IoL Min 0.5 0,10 — 10 1.6 1.5 1.1 0.9 1.3 2.6 — Output High (Source) Current, IoH Min 4.8 0,5 — 5 -0.64 -0.61 -0.42 -0.36 -0.51 -1 — 2.5 0,5 — 5 -0.64 -0.61 -0.42 -0.36 -0.51 -1 — 2.5 0,5 — 5 -0.64 -0.61 -0.42 -0.36 -0.51 -1 — 9.5 0,10 — 10 -1.8 -1.5 -1.1 -0.9 -1.3 -2.6 — - 0,15 — 15 -4.2 -4 -2.8 -2.4 -3.4 -6.8 — - 0,10 — 10 0.05 — 0 0.05 - 0,15 — 15 0.05 — 0 0.05 - 0,15 —			_	0,15	5	15	5	5	8	6	_	2.5	5	
Output High (Source) Current, I _{OH} Min 0.5	-	• •	0.4	0.5	_	5	0.64	0.61	0.42	0.36	0.51	1	_	
Output High (Source) 4.8 0.5 - 5 -0.64 -0.61 -0.42 -0.36 -0.51 -1	Current, IO	L Min	0.5	0,10	_	10	1.6	1.5	1.1	0.9	1.3	2.6	_	1
Current, I OH Min 2.5			1.5	0, 15		15	4.2	4	2.8	2.4	3.4	6.8	_	1 .
1.5		•	4.6	0,5	-	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	mA
13.5 0,15 - 15 -4.2 -4 -2.8 -2.4 -3.4 -6.8 - 0.05 - 0	Current, IO	H Min	2.5	0,5	_	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	
Output Voltage: — 0,5 — 5 0.05 — 0 0.05 Low-Level, VOL Max — 0,10 — 10 0.05 — 0 0.05 — 0,15 — 15 0.05 — 0 0.05 — 0,15 — 15 0.05 — 0 0.05 — 0,15 — 15 0.05 — 0 0.05 — 0,15 — 10 9.95 4.95 5 — — 0,10 — 10 9.95 9.95 10 — — 0,15 — 15 14.95 14.95 15 — Input Low Voltage, VIL Max Note 1 TTL-CMOS 1 — 5 15 0.8 — — 0.8 V CMOS-CMOS 1.5 — 5 15 1.5 — — 1.5 — —			9.5	0, 10		10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6		
Low-Level, Vol. Max			13.5	0,15	_	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_	
Output Voltage: High-Level, VOH Min TTL-CMOS TTL-CMOS	Output Volta	ge:		0,5		5	0.05				_	0	0.05	
Output Voltage: High-Level, VOH Min	Low-Level,	V _{OL} Max	_	0,10	_	10		0.0	05		.—	0	0.05	1
High-Level, V _{OH} Min - 0, 10 - 10 9.95 9.95 10 - - 0, 15 - 15 14.95 15 - Input Low Voltage, V _{IL} Max Note 1 TTL-CMOS			_	0, 15	_	15	-	0.0	05			0	0.05	1
TTL-CMOS 1 - 5 10 0.8 - - 0.8 V	Output Volta	ge:	_	0,5		5		4.9	95		4.95	5	_	1
Input Low Voltage,	High-Level,	V _{OH} Min		0,10		10		9.9	95		9.95	10	_	1 1
Voltage, V _{IL} Max Note 1			_	0, 15	_	15		14.	95		14.95	15	_	1
VIL Max Note 1 TIL-CMOS 1 - 5 15 0.8 - - 0.8 V CMOS-CMOS 1 - 5 10 1.5 - - 1.5 CMOS-CMOS 1.5 - 5 15 15 - - 1.5 CMOS-CMOS 1.5 - 10 15 3 - - 3 Input High Voltage, VIH Min Note 1 TTL-CMOS 9 - 5 10 2 2 - - CMOS-CMOS 9 - 5 10 3.5 2 2 - - CMOS-CMOS 13.5 - 5 15 3.5 3.5 - - CMOS-CMOS 13.5 - 5 15 3.5 3.5 - - CMOS-CMOS 13.5 - 5 15 7 7 - -	Input Low	TTL-CMOS	1		5	10		0.	.8		_	_	0.8	1
Note 1		TTL-CMOS	1	_	5	15		0.	.8		_		0.8	l v
CMOS-CMOS 1.5 - 10 15 3 - 3 3 3 3 3 4 3 3 4 4		CMOS-CMOS	1	_	5	10		1.	.5				1.5	1
Input High Voltage, VIH Min Note 1 TTL-CMOS 9 - 5 10 2 2 - -		CMOS-CMOS	1.5		5	15		1.	5		_		1,5	1
Input High Voltage, VIH Min Note 1 TTL-CMOS 9 - 5 10 2 2 - -		CMOS-CMOS	1.5	_	10	15		3	3			_		1
Voltage, V _{IH} Min Note 1 TTL-CMOS 13.5 — 5 15 2 2 — — CMOS-CMOS 9 — 5 10 3.5 3.5 — — CMOS-CMOS 13.5 — 5 15 3.5 3.5 — — CMOS-CMOS 13.5 — 10 15 7 7 — —	Input High	TTL-CMOS	9	_	5	10		2	2		2	_	<u> </u>	1
VIH Min Note 1 CMOS-CMOS 9 - 5 10 3.5 3.5 - - CMOS-CMOS 13.5 - 5 15 3.5 3.5 - - CMOS-CMOS 13.5 - 10 15 7 7 - -		TTL-CMOS	13.5	_	5	15	,							1
CMOS-CMOS 13.5 — 5 15 3.5 3.5 — — CMOS-CMOS 13.5 — 10 15 7 7 — —		CMOS-CMOS	9		5	10			·					
CMOS-CMOS 13.5 — 10 15 7 7 — —												<u> </u>		1
													_	1
Input Current, I _{IN} Max $-$ 0, 18 $-$ 18 \pm 0.1 \pm 0.1 \pm 1 \pm 1 $ \pm$ 10 ⁻⁵ \pm 0.1 \pm A	Input Current	1	_	0,18		18	±0.1	±0.1	±1	+1		±10 ⁻⁵	+01	^

Note 1: Applies to the 6 input signals. For mode control (P13), only the CMOS-CMOS ratings apply.

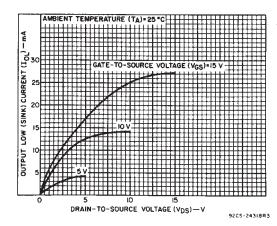


Fig. 2 - Typical output low (sink) current characteristics.

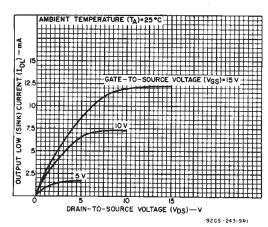
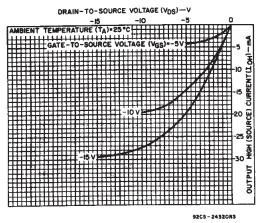


Fig. 3 - Minimum output low (sink) current characteristics.

CD4504B Types



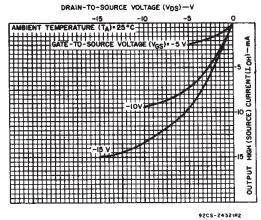


Fig. 4 - Typical output high (source) current characteristics.

Fig. 5 - Minimum output high (source) current characteristics.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	VDD	LIM	ITS	UNITS	
OHARACIERISTIC	(V)	Min.	Max.	0.41.73	
Supply-Voltage Range (For T _A = Full Package-Temperature Range)	_	5	18	٧	

DYNAMIC ELECTRICAL CHARACTERISTICS, At TA = 25°C; Input tr,tf = 20 ns, CL = 50 pF, RL = 200 Ω

CHARACTERISTI		SHIFTING MODE	VCC (V)	VDD (V)	LIM	IITS	UNITS
OTIANACT ENIST		SHIFTING MODE	100(1)	VUD (V)	TYP.	MAX.	UNITS
		TTL to CMOS	5	10	140	280	
		V _{DD} > V _{CC}	5	15	140	280	
Propagation Delay:	ſ	CMOS to CMOS	5	10	120	240]
High-to Low,	t _{PHL}	$V_{DD} > V_{CC}$	5	15	120	240	
		. *	10	15	70	140	
	ſ	CMOS to CMOS	10	5	275	550	
		$V_{CC} > V_{DD}$	15	5	275	550	
			15	10	70	140	
		TTL to CMOS	5	10	140	280	ns
	1	V _{DD} > V _{CC}	5	15	140	280	
	[CMOS to CMOS	5	10	120	240	7
Low-to-High,	telH	$V_{DD} > V_{CC}$	5	15	120	240	
	21		10	15	70	140	
		CMOS to CMOS	10	5	200	400	
		Vcc > Vpp	15	5	200	400	
	A + " " "		15	10	60	120	
	1		1	5	100	200	
Transition Time,	t _{THL} ,t _{TLH}	All Modes		10	50	100	
				15	40	80	
Input Capacitance,	Cin	Any Input		5	7.5	pF	

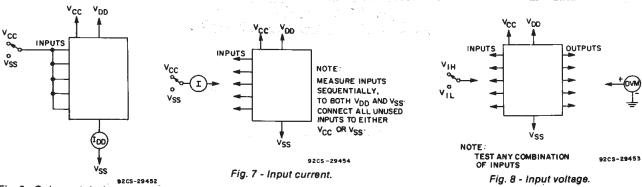


Fig. 6 - Quiescent device current.

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CD4504B Types

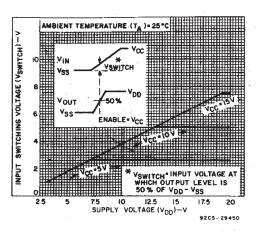


Fig. 9 - Typical input switching as a function of high-level supply voltage.
(SELECT at Vcc-CMOS mode).

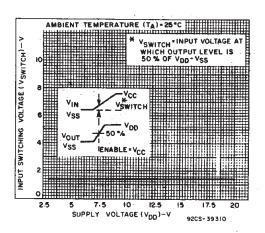


Fig. 10 - Typical input switching as a function of high-level supply voltage (SELECT at Vss-TTL mode).

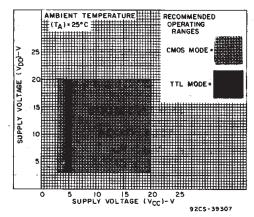
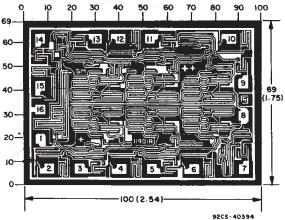


Fig. 11 - High-level supply voltage vs. low-level supply voltage.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and pad layout for CD4504BH.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4504BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4504BE	Samples
CD4504BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4504BE	Samples
CD4504BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4504BF3A	Samples
CD4504BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	Samples
CD4504BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	Samples
CD4504BM96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	Samples
CD4504BME4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	Samples
CD4504BMG4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	Samples
CD4504BMT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	Samples
CD4504BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B	Samples
CD4504BPWE4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B	Samples
CD4504BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

PACKAGE OPTION ADDENDUM

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(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4504B, CD4504B-MIL:

Catalog: CD4504B

■ Enhanced Product : CD4504B-EP, CD4504B-EP

Military: CD4504B-MIL

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

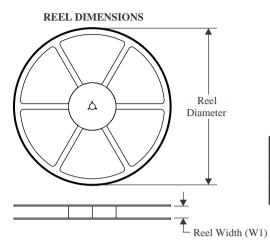
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

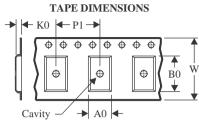
Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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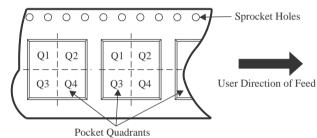
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

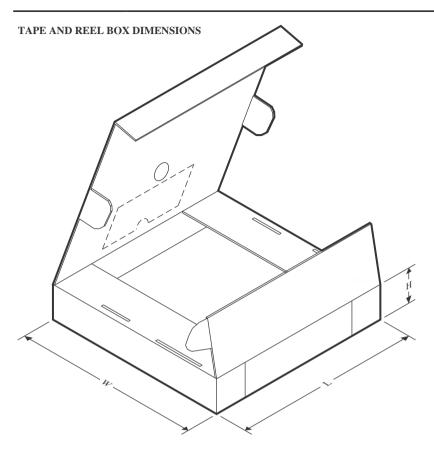


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4504BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4504BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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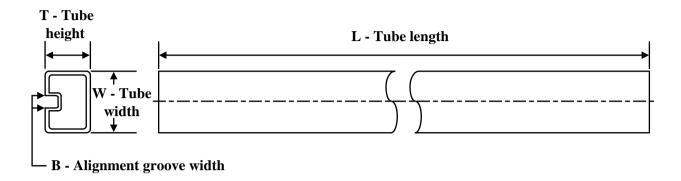
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4504BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4504BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BM	D	SOIC	16	40	507	8	3940	4.32
CD4504BME4	D	SOIC	16	40	507	8	3940	4.32
CD4504BMG4	D	SOIC	16	40	507	8	3940	4.32
CD4504BPW	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4504BPWE4	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE

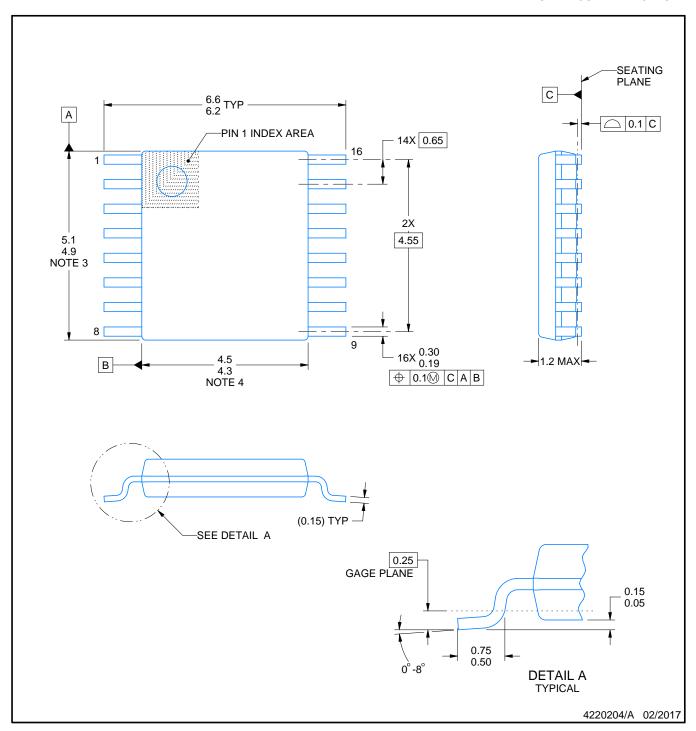


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



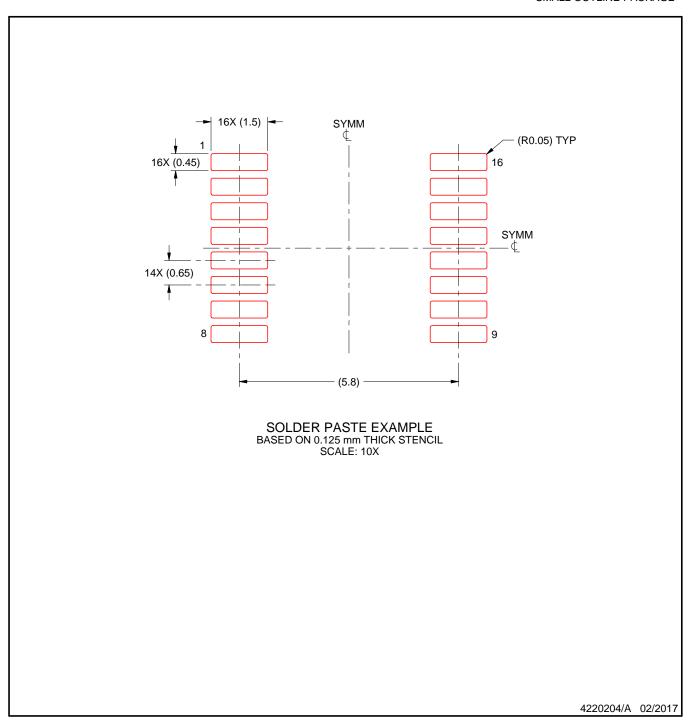
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE

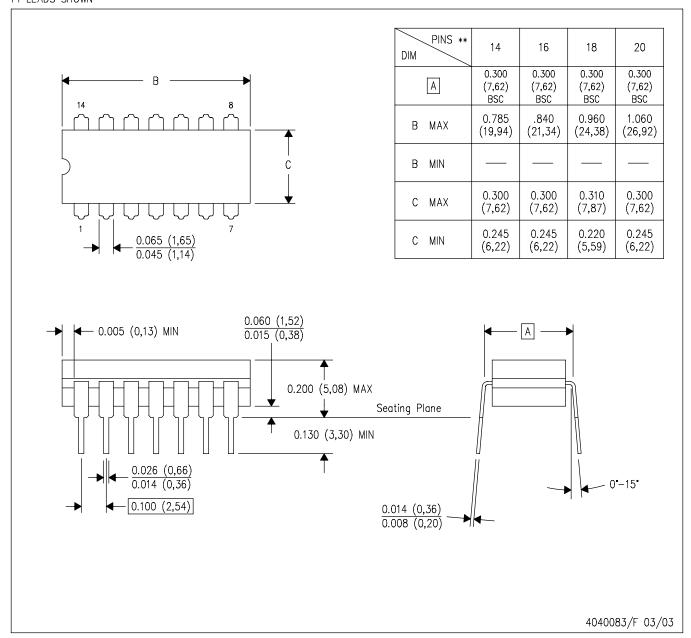


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



14 LEADS SHOWN

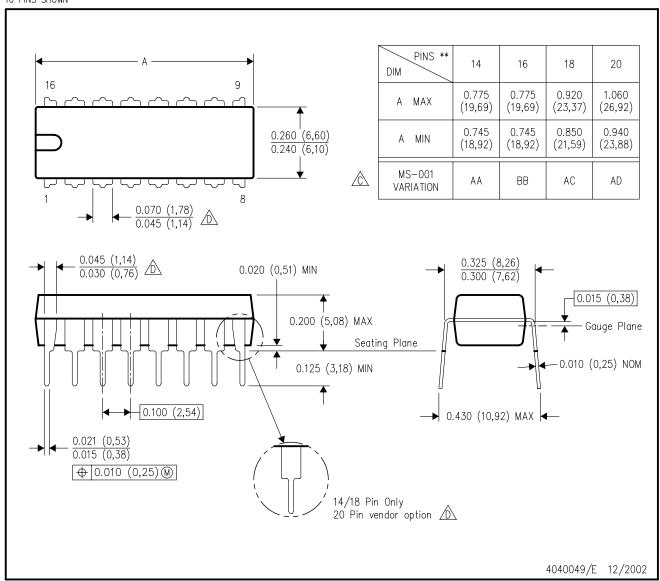


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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